SYSTEMATIC STUDY OF PYROELECTRICITY

Light Scattering and Pyroelectricity in Ferroelectrics

M. I. Bell and P. M. Raccah
Yeshiva University
Belfer Graduate School of Science
2495 Amsterdam Avenue
New York, New York 10033

April 1976

Interim Report for Period 1 April 1975 - 30 September 1975

Approved for public release; distribution unlimited

Sponsored by

ADVANCED RESEARCH PROJECTS AGENCY
1400 Wilson Blvd.
Arlington, VA 22209
ARPA Order No. 2573

US Army Electronics Command
Fort Monmouth, NJ 07703

The views and conclusions contained in this document are those of the authors and should not be interpreted as necessarily representing the official policies, either expressed or implied, of the Advanced Research Projects Agency or the U.S. Government.
NOTICES

Disclaimers

The findings in this report are not to be construed as an official Department of the Army position, unless so designated by other authorized documents.

The citation of trade names and names of manufacturers in this report is not to be construed as official Government indorsement or approval of commercial products or services referenced herein.

Disposition

Destroy this report when it is no longer needed. Do not return it to the originator.
The results of two studies of pyroelectric materials are reported. In the first, a Raman scattering study of KNbO₃, anomalous scattering is found which can be related directly to the dynamic disorder which has been invoked to explain the results of earlier x-ray and neutron scattering studies and which provides the starting point for the generalized molecular field theory of ferroelectricity proposed elsewhere by the authors. The second is an analysis of the physical properties of pyroelectric materials which determine their performance as vidicon targets. The role of thermal diffusion is assessed and
20. Abstract (cont'd)

found to be independent of the dielectric parameters which determine the signal-to-noise figure of merit. Examination of the figures of merit relevant to vidicon operation in the anode potential stabilized and cathode potential stabilized modes shows that among proper ferroelectrics substantial (i.e. order-of-magnitude) improvement over presently available materials is impossible in the first case and highly unlikely in the second.
## CONTENTS

<table>
<thead>
<tr>
<th>Section</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>I. Introduction</td>
<td>1</td>
</tr>
<tr>
<td>II. Anomalous Scattering and Asymmetrical Line Shapes in Raman Spectra of KNbO₃</td>
<td>5</td>
</tr>
<tr>
<td>III. Assessment of Pyroelectric Materials for Vidicon Applications</td>
<td>27</td>
</tr>
</tbody>
</table>
I. INTRODUCTION

The work described in this report was conducted from 1 April 1975 to 30 September 1975 under Advanced Research Projects Agency contract DAAB 07-74-C-0470, P.M. Raccah, principal investigator, F. Rothwarf and G. Lafrate, contract monitors. The purpose of this investigation is to elucidate the physical mechanism responsible for the pyroelectric effect and to assess the extent to which this effect can be exploited in the construction of infrared detectors and imaging devices. In previous reports and publications we have proposed\(^1\) and elaborated on\(^2\) a generalized molecular field theory (GMFT) of ferroelectricity and pyroelectricity which provides a quantitative basis for study of those pyroelectric materials which are also ferroelectric. An underlying assumption of the GMFT is the existence of elementary dipoles which persist (although in a disordered state) at temperatures well above the ferroelectric-to-paraelectric transition, even in so-called displacement ferroelectrics. In the spring of 1974, an experimental study of KNbO\(_3\), a typical displacement ferroelectric, was begun in collaboration with A.M. Quittet and M. Lambert in order to determine whether effects attributable to the presence of such dipoles could be observed in the Raman scattering spectra. This proved indeed to be the case, and preliminary results were reported at a meeting of the American Physical Society\(^4\). To complete the experimental picture, especially with respect to the temperature dependence of the Raman spectra, further studies were made in collaboration with M. Krauzman, and Section II of this report consists of a paper describing this work which has been submitted to Solid State Communications. The detailed results presented there fully confirm the preliminary findings\(^4\) and provide further evidence for the validity of the assumptions on which the GMFT is based.
With respect to the use of pyroelectric materials in infrared detection, our earlier work\textsuperscript{1,5} had shown that both the GMFT and more fundamental thermodynamic arguments could be used to study the signal-to-noise figures of merit of pyroelectric materials used in small-area detectors and vidicons. A detailed treatment of the vidicon case was carried out, and the results were discussed in a paper\textsuperscript{6}, presented to the 1975 International Electron Devices Meeting and reproduced as Section III of this report. This study concluded that while the thermal diffusivity of the target material plays a significant role in determining vidicon performance, this parameter can be treated independently of the figure of merit, and improved performance can be obtained by selecting a material with a low Debye temperature.

More significantly, quantitative predictions of the figures of merit of pyroelectric materials in vidicon applications were obtained. Different figures of merit are relevant to the two commonly used modes of vidicon operation, anode potential stabilization (APS) and cathode potential stabilization (CPS). For the APS mode we were able to show, using purely thermodynamic arguments, that an upper bound exists for the figure of merit which is only a factor 2.5 greater than the largest value yet obtained experimentally. In the CPS case, the GMFT was used with extreme but still physically reasonable values of its parameters, chosen to give the largest possible figure of merit. The result was only a factor of three greater than the best value currently available. The CPS result is subject of course to any limitations which may exist to the validity of the GMFT. It is restricted, for example, to so-called proper ferroelectrics, in which the polarization is the order parameter of the
ferroelectric phase transition. Improper ferroelectrics, in which the spontaneous polarization arises indirectly, via a coupling to the actual order parameter, may yield higher values of this figure of merit than are predicted by the GMFT and are well worth investigating from that point of view.
References

5. M.I. Bell and P.M. Raccah, unpublished.
II. ANOMALOUS SCATTERING AND ASYMMETRICAL LINE SHAPES IN RAMAN SPECTRA OF ORTHORHOMBIC KNbO$_3$

by

A. M. Quittet
Laboratoire de Physique des Solides
Université Paris-Sud, Orsay

M. I. Bell
Physics Department
Yeshiva University
New York, New York

M. Krauzman
Département de Recherches Physiques
Laboratoire Associé au CNRS No. 71
Université, Paris VI

and

P. M. Raccah
Physics Department
Yeshiva University
New York, New York
The Raman spectrum of orthorhombic KNbO₃ is found to contain anomalous scattering, consisting of a large background and broad bands, which can be related directly to the dynamic disorder which has been invoked to explain the results of earlier studies of diffuse x-ray scattering and inelastic neutron scattering. Some ordinary first order lines exhibit coupling to the anomalous part of the spectrum which is revealed by the existence of resonant interference of the type described by Fano. All these features disappear abruptly at the transition to the low-temperature, rhombohedral phase, indicating that they are characteristic of the peculiar dynamics of linear chains observed in the orthorhombic, tetragonal, and cubic phases.
INTRODUCTION

In the ferroelectric perovskites such as BaTiO$_3$ and KNbO$_3$, x-ray diffuse scattering$^1$ and inelastic neutron scattering$^2,3$ experiments yield evidence of a very large anisotropy in the dispersion of some of the vibrational modes. Light scattering$^4,5$ has been used to investigate the zone-center phonons in order to check the soft mode theories$^6$. We report here some new results of Raman scattering experiments performed on a single-domain KNbO$_3$ sample, both in its room temperature orthorhombic phase and as the temperature is lowered through the orthorhombic to rhombohedral phase transition.

The assignment of the ordinary first order lines is quite easily obtained, leaving outside this classification a large continuous scattering which we refer to as "anomalous". The latter, previously described in Ref. 5 for restricted scattering geometries, has now been found to occur more generally whenever the incident and scattered beams propagate perpendicular to the Z-axis and are simultaneously polarized parallel to Z. As expected, this anomalous spectrum disappears abruptly at the orthorhombic to rhombohedral transition temperature, as does the normal low frequency $B_2(T0)$ line. In the spectra where the anomalous scattering occurs, some first order lines display an asymmetrical shape characteristic of a "Fano interference"$^7$.

EXPERIMENTAL

The Raman scattering was excited by an argon-ion laser operating at either 4880 Å or 5135 Å. Measurements were made using a $\frac{1}{2}$-meter Spex double grating spectrometer located at the Maybaum Institute of Yeshiva University and a Codberg T800 triple grating spectrometer located at Département de Recherches Physiques, Université Paris VI. Both systems
employed photon counting detection.

We used a single-domain sample cut with the faces perpendicular to the orthorhombic axes. Standard right-angle and back-scattering geometries were used to obtain various linear momentum transfers from the photons to the crystals. Table I summarizes the modes which can be observed in each scattering geometry. The orthorhombic axes are related to the pseudocubic ones as described in Fig. 1. At zero wavevector, the irreducible representations of the 12 optic modes in the $C_{2v}$ point group of the orthorhombic phase are as follows: $4 A_1(X), 4 B_1(Y), 3 B_2(Z), 1 A_2$. All $A_1$, $B_1$ and $B_2$ modes are infrared active (the letters in parentheses indicate the direction of the dipole moment of each mode), and for these the longitudinal or transverse character must be considered. Two features of this table should be noted. First, $B_1$ and $B_2$ modes are not detected in a longitudinal configuration. Second, when a polar mode is neither transverse nor longitudinal in a given scattering geometry (labelled "mixed"), it loses its zero wavevector irreducible representation species through mixing with modes of different symmetry.

**ROOM TEMPERATURE SPECTRA**

All the spectra listed in Table I have been recorded. Only those of special interest are reproduced in Figures 2 and 3. In Fig. 2, the peaks which arise from contamination by other species are drawn with broken lines.

From Table I, and taking into account the possible mixing of species, we can assign the observed frequencies to the different modes. These assignments are summarized in Table II. Within the limit of experimental accuracy, we agree with the results published independently by Winter et al. at least for those lines identified unambiguously in Ref. 5. The following details should be noted. The low frequency $B_2$(TO) line (maximum at 40 cm$^{-1}$) is broad and asymmetrical (Fig. 2a), and a thin line at 195 cm$^{-1}$ which sits
on its tail is slightly distorted and seems to show a dip on the low frequency side. In the $B_2$-mixed spectrum, the lines at 170 and 205 cm$^{-1}$ display an interference dip between them (Fig. 2b).

The anomalous spectrum is seen in the following geometries: Y(ZZ)Y, X(ZZX) and X(ZZ)Y. These are $A_1$ (TO), $A_1$ (LO), and $A_1$ (mixed) spectra, respectively, and are shown in Fig. 3e, a, c. In each case, the linear momentum transfer is perpendicular to the Z axis, and the light beams are polarized parallel to Z. The anomalous scattering, identical in the three spectra, consists of a continuous background, decreasing in intensity from low to high frequency, and two broad bumps centered near 130 and 430 cm$^{-1}$.

The ordinary first order lines are superimposed on the anomalous spectrum, but some of them show a coupling leading to an asymmetrical line-shape and interference dip. This is clearly demonstrated by comparison of the pairs of spectra in Fig. 3:

i) Fig. 3a and 3b: The normal X(YY)X spectrum together with the anomalous X(ZZ)X one are both $A_1$ (LO) spectra. Note the lines at 195 and 435 cm$^{-1}$.

ii) Fig. 3d and 3e: The normal Y(XX)Y spectrum together with the anomalous X(ZZ)Y one are both $A_1$ (TO) spectra. Note the line at 193 cm$^{-1}$.

iii) Fig. 3c: The anomalous X(ZZ)Y spectrum has $A_1$ (mixed) symmetry. Note the mode at 420 cm$^{-1}$ which appears almost wholly negative in the anomalous part of the spectrum.

**TEMPERATURE DEPENDENCE**

As the temperature is lowered, there is essentially no change in the low frequency $B_2$ (TO) line and the anomalous spectrum until the transition temperature is reached. The frequency and width of the $B_2$ line both
decrease slightly, but its intensity (Fig. 4a), as well as the shape and intensity of the anomalous spectrum, remains unchanged. Below the phase transition, which takes place near $-59^\circ C$, the spectrum becomes very different (Fig. 4b, c) as the broad $B_2$ line and the anomalous scattering disappear completely. Since the sample becomes broken and twinned, all the spectra are superimposed, so that it is not possible to miss any lines. Upon reheating the sample, the anomalous spectra of the orthorhombic phase appear again at $-30^\circ C$, exhibiting the large thermal hysteresis characteristic of a first order transition. These experiments thus demonstrate that the anomalous spectrum is related to an intrinsic property of the orthorhombic phase, as is the low frequency $B_2(\Gamma 0)$ line.

**DISCUSSION**

We note first that all the anomalous features which appear in Raman, neutron, and x-ray scattering experiments occur only when the linear momentum transfer lies perpendicular to the Z-axis, and that these features disappear in the rhomboedral phase. Hence the dynamical properties of the orthorhombic phase have a pronounced one-dimensional character. These results can be understood as arising from displacements of the niobium atoms in the Z direction (away from the $C_2$ symmetry axis) which are correlated for some finite distance along Z. Averaged over distances large compared to this correlation length, however, the structure retains orthorhombic symmetry. Such disorder need not be static, since its effects will be seen in scattering experiments provided the lifetime of the local departure from the average symmetry is greater than the scattering time. From this point of view, the anomalous features in the Raman spectra can be interpreted as disorder-induced first-order scattering, i.e. one-phonon scattering by modes which would not be Raman active in a
perfect crystal but which become so when both the translational and point-group symmetries are broken by the disorder. Since all phonons (not only those at the zone center) can become Raman active in this way, one anticipates a scattering spectrum proportional, in first approximation, to the one-phonon density of states. This interpretation is further strengthened by the fact that neutron scattering results\textsuperscript{3} suggest the existence of a peak in the one-phonon density of states near 150 cm\textsuperscript{-1}, close to one of the peaks (130 cm\textsuperscript{-1}) in the anomalous Raman spectra.

We have studied the modification of the spectra which occurs as the linear momentum transfer is rotated from the Y direction to the Z direction. As the momentum transfer is changed, the intensity of the anomalous scattering decreases rapidly, while the frequency of the $B_2$ line shifts very rapidly toward higher values (Fig. 5a,b). We conclude from this that the $B_2$ line is produced by an underdamped zone-center phonon with a large $\Gamma_0$-$\Gamma_0$ frequency difference and that the anomalous spectrum in ZZ polarization arises from a continuum of states. Our identification of the line at 40 cm\textsuperscript{-1} as the zone-center $B_2(TO)$ phonon is consistent with the results of neutron scattering experiments.\textsuperscript{3}

Although Currat et al\textsuperscript{3} extrapolate the frequency of the optical branch to about 25 cm\textsuperscript{-1} at the zone center, the experimental resolution is such that spectra near the zone center and at low frequencies are always heavily contaminated by the Bragg peak and the acoustic dispersion. Moreover, the experimental points closest to the zone center could only be obtained from constant energy scans which do not provide an accurate measure of mode frequency.

The asymmetrical line shapes observed in this work are of two types.
One is produced by the small interference between the two lowest-lying lines in the \(E_2(T0)\) spectrum (Fig. 2a). This is merely a coupling between modes of identical symmetry, which appears because of the large width of the low-frequency line. The coupling becomes much stronger when the wavevector is rotated 45° from the Y axis toward the Z axis, since the rapid increase in the frequency of the lower mode brings the two modes quite close (Fig. 2b).

The second type of asymmetry can be seen in the shape of several narrow lines observed in the anomalous ZZ spectra. This can be analyzed, using a formalism developed by Fano\(^7\), as an interference between the scattering by a discrete, one-phonon state and a continuum of states. Such line shapes have been reported previously in BaTiO\(_3\) by Rousseau and Porto\(^9\) and in heavily doped silicon by Cerdeira et al\(^10\). The application of Fano's formalism to Raman scattering has been treated in detail by Scott\(^11\). If the Hamiltonian \(H\) couples a discrete state \(\varphi\) with a continuum \(\psi_E\) according to

\[
\begin{align*}
\langle \varphi | H | \varphi \rangle &= E_\varphi \\
\langle \psi_E | H | \varphi \rangle &= V_E \\
\langle \psi_E | H | \psi_E \rangle &= E \delta(E-E'),
\end{align*}
\]

then the observed scattering cross section \(\sigma\) is related to the cross section \(\sigma_E\) which would be produced by the continuum in the absence of any coupling by

\[
\sigma = \frac{(g+\varepsilon)^2}{1+\varepsilon^2} \sigma_E.
\]
Here $\epsilon = (E - E_\varphi - \delta E)/\Gamma$ is a reduced energy variable involving the half-width $\Gamma = \pi |V_E|^2$ and energy shift $\delta E = \pi^{-1} \int dE' \Gamma/(E-E')$

($\Theta$ indicates "principal part of") of the "resonant" state resulting from the discrete-continuum interaction. The parameter

$q = (\tau_E)^{-1} \langle \Psi_i | \alpha_{ij} | i \rangle / \langle \Psi_i | \alpha_{ij} | i \rangle$

depends on the matrix elements of the Raman tensor $\alpha_{ij}$ for transitions from an initial state $|i\rangle$ to the continuum $\Psi_E$, and to the state $\Psi = \varphi + \Theta \int dE' V_E \Psi_E/(E-E')$, which is the discrete state $\varphi$ modified by an admixture of continuum states. If $q$ and $\Gamma$ are independent of $E$ in a sufficiently large interval around $E_\varphi$, the spectrum can be fitted to Eq. (2) with $q$ and $\Gamma$ treated as (energy-independent) fitting parameters. (Note that $\Gamma$ and $q$ cannot be completely independent of energy unless $\delta E = 0$.) Figure 6 compares the experimental $X(YY)\bar{X}$ spectrum near 430 cm$^{-1}$ with the prediction of Eq. (2) to which a slowly varying background has been added. A good fit is obtained for $q = 0.75$, $\Gamma = 3.6$ cm$^{-1}$, $E_\varphi + \delta E = 432.7$ cm$^{-1}$. The value of $E_\varphi$ obtained from the $X(YY)\bar{X}$ spectrum (Fig. 3b) is 430 cm$^{-1}$, yielding a shift $\delta E = 2.7$ cm$^{-1}$ due to the coupling. The exact nature of this coupling remains to be determined. If, as we have proposed, the continuum is produced by disorder-induced first-order scattering, it may be coupled to zone-center modes via anharmonic terms in $H$ as discussed by Scott or via additional terms which depend directly on the disorder.

CONCLUSION

The experiments described here demonstrate that a major part of the dynamical behavior of orthorhombic KNbO$_3$ is one-dimensional in character and consistent with the formation of linear chains of correlated displacements of niobium ions as proposed in connection with diffuse x-ray scattering.
results\(^1\) and Raman scattering studies of the cubic and tetragonal phases\(^5\).

This further evidence of disorder in the orthorhombic phase, together with the observation that the lowest \(B_2(T0)\) mode does not display any significant softening with decreasing temperature, strongly suggests that the phase transitions of \(KNbO_3\) (including the ferroelectric-paraelectric one) have some order-disorder character. Such a suggestion is not inconsistent with the fact that the transitions are thermodynamically of first order, since recent studies\(^12\) of systems of dipoles interacting via a generalized molecular field have shown that first-order transitions are possible in such a model and that an accurate quantitative description of the cubic-tetragonal transition in \(BaTiO_3\) can be obtained.

**ACKNOWLEDGMENTS**

We are indebted to Mr. Fluckinger of the Laboratorium für Festkörperphysik, ETH Zurich who provided us with the excellent single-domain \(KNbO_3\) sample, to Prof. M. Lambert for helpful discussions, and to Mr. Hamel for technical assistance. The work at Yeshiva University was supported by the Advanced Research Projects Agency.
References

8. Similar results have been reported recently by M. P. Fontana and C. Razzetti, Solid St. Comm. 17, 377 (1975).
TABLE CAPTIONS

Table I. Summary of the scattering geometries employed and the mode symmetries observed. Scattering geometries are indicated by the conventional notation $k_1(\hat{e}_1, \hat{e}_2) k_2$, where $k_1, \hat{e}_1 (k_2, \hat{e}_2)$ are the wavevector and polarization vector of the incident (scattered) photon.

Table II. Frequencies and symmetry assignments of first-order Raman lines of KNbO₃. The figure in parentheses is the full width of the line at half maximum.
<table>
<thead>
<tr>
<th>Incident wave vector</th>
<th>Scattered wave vector</th>
<th>Momentum transfer ( k_s - k_i )</th>
<th>Polarization of incident and scattered beams ( \vec{e}_i \vec{e}_s ) and mode symmetry</th>
</tr>
</thead>
<tbody>
<tr>
<td>( \vec{k}_i )</td>
<td>( \vec{k}_s )</td>
<td>( \vec{k}_s - \vec{k}_i )</td>
<td>( XX )    ( YY )    ( ZZ )    ( YX, XY )    ( ZX, XZ )    ( YZ, ZY )</td>
</tr>
<tr>
<td>( X )</td>
<td>( Y )</td>
<td>( \perp Z )</td>
<td>( -- )    ( -- )    ( \text{mixed} )    ( \text{mixed} )    ( \text{TO} )    ( \text{indiff.} )</td>
</tr>
<tr>
<td>( Y )</td>
<td>( Z )</td>
<td>( \perp X )</td>
<td>( \text{TO} )    ( -- )    ( -- )    ( \text{mixed} )    ( \text{mixed} )    ( \text{indiff.} )</td>
</tr>
<tr>
<td>( X )</td>
<td>( Z )</td>
<td>( \perp Y )</td>
<td>( -- )    ( \text{mixed} )    ( \text{TO} )    ( \text{mixed} )    ( \text{indiff.} )</td>
</tr>
<tr>
<td>( X )</td>
<td>( X )</td>
<td>( \parallel X )</td>
<td>( -- )    ( \text{LO} )    ( \text{LO} )    ( -- )    ( -- )    ( \text{indiff.} )</td>
</tr>
<tr>
<td>( Y )</td>
<td>( Y )</td>
<td>( \parallel Y )</td>
<td>( \text{TO} )    ( -- )    ( \text{TO} )    ( -- )    ( -- )    ( -- )    ( -- )</td>
</tr>
<tr>
<td>( Z )</td>
<td>( Z )</td>
<td>( \parallel Z )</td>
<td>( \text{TO} )    ( \text{TO} )    ( -- )    ( \text{TO} )    ( -- )    ( -- )    ( -- )    ( -- )</td>
</tr>
</tbody>
</table>
### TABLE II

<p>| | | | | | |</p>
<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>$A_1$(TO)</td>
<td>$A_1$(LO)</td>
<td>$B_1$(TO)</td>
<td>$B_2$(TO)</td>
<td>$A_2$</td>
<td></td>
</tr>
<tr>
<td>193. (2)</td>
<td>194.5 (3)</td>
<td>192 (2)</td>
<td>40 (27x2)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>249 (25)</td>
<td>270</td>
<td></td>
<td>1.56.5*</td>
<td></td>
<td></td>
</tr>
<tr>
<td>295 (5)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>297 (5)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>434.5* (10)</td>
<td>513 (20)</td>
<td>534 (20)</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>606.5(33)</td>
<td>834(27)</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

* Lines showing an asymmetrical shape in at least one scattering geometry.
FIGURE CAPTIONS

Fig. 1. Orthorhombic axes for KNbO$_3$ and corresponding pseudocubic axes (in brackets). Also shown are the symmetry elements of the C$_{2v}$ point group. The spontaneous polarization is in the X direction.

Fig. 2. $B_2$ symmetry spectra: a) $B_2$(TO) in back-scattering geometry, b) $B_2$ (mixed) in right-angle geometry. The dashed lines indicate contamination from other symmetry species due either to a small misorientation of the polarizers or to mixing of polar modes as described in the text.

Fig. 3. Anomalous spectra and the associated normal spectra. In the $Y(XX)\overline{Y}$ and $Y(ZZ)\overline{Y}$ spectra, the broad line in the vicinity of 50 cm$^{-1}$ is most probably a contamination from the $Y(XZ)\overline{Y} B_2$(TO) spectrum due to the divergence of the scattered beam.

Fig. 4. Temperature dependence of part of the $B_1 + B_2$ spectrum: a) in the orthorhombic phase just above the phase transition (temperature decreasing), b) in the rhombohedral phase just below the transition (temperature decreasing), c) in the rhombohedral phase in the hysteresis interval (temperature increasing).

Fig. 5. a) $B_2$ spectrum for a momentum transfer rotated by 15$^\circ$ from a TO configuration toward the LO configuration. b) Anomalous spectrum for the same momentum transfer.
Fig. 6. Comparison of the experimental $X(ZZ)\bar{X}$ spectrum (solid curve) with the prediction of Eq. (2) (dots).
Fig 2 (a,b)
ASSESSMENT OF PYROELECTRIC MATERIALS FOR VIDICON APPLICATIONS

M. I. Bell and P. M. Raccah
Yeshiva University
Physics Department
New York, New York

ABSTRACT

An analysis is made of the physical properties of pyroelectric materials which determine their performance as vidicon targets. Particular attention is paid to three factors: (1) signal-to-noise figure of merit, (2) thermal diffusivity, and (3) target capacitance. It is shown that at room temperature or above, the first two quantities depend on different (essentially unrelated) physical parameters, so that their effects on overall resolution can be treated independently. Examination of the figures of merit relevant to vidicon operation in the anode potential stabilized and cathode potential stabilized modes shows that substantial (order-of-magnitude) improvement over presently available materials is impossible in the first case and highly unlikely in the second.
INTRODUCTION

In selecting a pyroelectric material for use as a vidicon target, three factors directly related to the physical properties of the material must be considered (1). They are: (1) the signal-to-noise figure of merit $M(n)$ in the absence of lateral thermal conduction in the target, (2) the thermal modulation transfer function $F$, which gives the fractional reduction in available pyroelectric signal due to thermal diffusion, and (3) the target capacitance, which, together with the impedance of the electron beam, determines the extent of image persistence (capacitive lag) caused by incomplete readout of the pyroelectric charge. For operation at or above room temperature, the first two factors can be shown to depend on different physical properties, making it possible to consider them independently. In the case where capacitive lag is the limiting factor in the resolution, its effects can be taken into account by a suitable modification of the figure of merit (1).

FIGURE OF MERIT

The figure of merit of a pyroelectric material used as a vidicon target depends on the method chosen for signal readout (2). The two methods which have been employed to date are anode potential stabilization (APS) and cathode potential stabilization (CPS). The figures of merit for these techniques can be summarized as (1):

$$M(n) = \frac{\alpha \varphi}{\rho c \varepsilon^n z^{1-n}},$$  \hspace{1cm} (1)

where

$\alpha =$ optical absorption coefficient
$\varphi =$ pyroelectric coefficient
$\rho =$ density
$c =$ specific heat per gram
$\varepsilon = 1+\varepsilon_m = $ static dielectric constant
$z =$ target thickness

The value of the exponent depends on the readout mode and amplifier bandwidth $\Delta f$:

$$n = \begin{cases} 
0 \text{ APS, } \Delta f > 2\text{MHz or CPS, } \Delta f > 1.5 \text{ MHz} \\
\frac{1}{2} \text{ APS, } \Delta f < 2\text{MHz} \\
1 \text{ CPS, } \Delta f < 1.5\text{MHz}
\end{cases}$$
The results of Taylor and Boot (2) indicate that the signal-to-noise ratio falls off so rapidly with increasing amplifier bandwidth that only the cases \( n = \frac{1}{2} \) and \( n = 1 \) are likely to be of practical interest with materials currently in use. Operation in the large bandwidth \( (n = 0) \) mode might be possible with materials having larger pyroelectric coefficients than triglycine sulfate (TGS), but all such materials now known have large dielectric constants and so would suffer from capacitive lag (1). As a result of these considerations, only \( M(\frac{1}{2}) \) and \( M(1) \) will be discussed here.

Since a vidicon target is operated in a closed circuit and at a high modulation (chopping or panning) frequency, the thermodynamic conditions require that the pyroelectric coefficient and specific heat at constant electric field and the adiabatic dielectric constant be used in Eq. (1). Then

\[
M(n) = \frac{\alpha \varphi_c}{C_p l z^n} \left( \frac{4m}{\varphi} \right)^{1-n}, \tag{2}
\]

where \( S \) is the entropy, \( \rho_c = \rho e_c \) is the volume specific heat, and we have used the fact that \( \rho \gg 1 \) in all cases of interest. The thermodynamic derivatives at constant field \( (C_p) \) and constant entropy \( (x_s) \) can be related to their counterparts at constant polarization \( (C_p) \) and constant temperature \( (x_p) \) by arguments analogous to those used for systems in which pressure and volume are the thermodynamic variables (3). One obtains the relations

\[
\frac{C_p}{C_p} = \frac{x_T}{x_S} = 1 + X, \tag{3}
\]

where \( X = T \frac{\varphi_c^2}{C_p x_T} \). The figure of merit is then given by

\[
M(n) = \frac{\alpha \varphi_c (1+X)^{n-1}}{C_p l z^n} \left( \frac{4m}{\varphi} \right)^{1-n}, \tag{4}
\]

and for \( n = \frac{1}{2} \) we find

\[
M(\frac{1}{2}) = \alpha (4mTC_p)^{-\frac{1}{2}} \left( \frac{X}{1+X} \right)^{\frac{1}{2}} \tag{5}
\]
Garn and Sharp (1) have used Eq. (1) to evaluate \( M(\frac{1}{2}) \) from the room-temperature experimental data for a number of crystals, assuming \( \alpha = 1 \) and a target thickness of \( z = 30 \, \mu m \). Their results are shown in Fig. 1, plotted as a function of \( (X/l+X)^{1/2} \). Figure 1 also gives results based on the data compiled by Garn and Sharp (1) for ceramics and polymers. For the polymers, \( M(\frac{1}{2}) \) was re-calculated using \( z = 30 \, \mu m \) instead of \( z = 6 \, \mu m \) to permit comparison with the results for ceramics and single crystals. Where necessary, \( C_p \) was estimated from measurements on closely related materials.

Figure 1 clearly demonstrates that \( M(\frac{1}{2}) \) is in fact proportional to \( (X/l+X)^{1/2} \), with essentially the same coefficient of proportionality for all materials reported in Ref. 1. Hence Eq. (5) can be written

\[
M(\frac{1}{2}) = M^*(\frac{1}{2}) \left( \frac{X}{l+X} \right)^{1/2}
\]  

where

\[
M^*(\frac{1}{2}) = \alpha \left( \frac{4\pi T C_P \rho}{x} \right)^{1/2}
\]

is the theoretical maximum figure of merit since \( (X/l+X)^{1/2} \) cannot exceed one. From a least-squares fit to the data in Figure 1, we find that \( M^*(\frac{1}{2}) = 20 \pm 2 \times 10^{-8} \, C\cdot cm^{1/2} / J \). To understand why \( M^*(\frac{1}{2}) \) as given by Eq. (7) should be effectively independent of the material chosen, we note first that since \( C_p \) is defined at constant polarization, it cannot contain any anomalous contribution from the ferroelectric polarization. So in a ferro-electric \( C_p \) can be identified with the ordinary lattice specific heat. Now at room temperature the lattice specific heat has very nearly reached its high-temperature limiting value of \( 3k \) per particle (\( k \) is Boltzmann's constant) in all but the few materials with exceptionally high Debye temperatures. Thus the specific heat per unit volume \( C_p \) depends only on the particle density, which is known to have essentially the same value (a few times \( 10^{22} \) particles per cubic centimeter) in all solids. If we take the particle density to be one tenth of Avogadro's number per cubic centimeter (i.e. \( 6 \times 10^{22} \, cm^{-3} \)) and again use \( T = 300 \, K \), \( \alpha = 1 \), \( \frac{z}{x} = 30 \, \mu m \), Eq. (7) gives

\[
M^*(\frac{1}{2}) = 20 \times 10^{-8} \, C\cdot cm^{1/2} / J
\]

in agreement with the experimental result reported above.
A second, perhaps more important fact to be noted in Fig. 1 is that L-alanine doped TGS (LATGS), the material with highest known value of $M(\frac{1}{2})$, reaches 40% of the theoretical limit $M^*(\frac{1}{2})$. Although this previously unrecognized fact is discouraging from the point of view of attempts to obtain larger absolute values of $M(\frac{1}{2})$, it does demonstrate the remarkable effect that doping or atomic substitution can have on the figure of merit (e.g. compare $X = 0.004$ for triglycine selenate (TGSe) with $X = 0.2$ for LATGS). These large variations in $X$ suggest that if a target material is selected for characteristics other than large $M(\frac{1}{2})$ (e.g. small dielectric constant, low thermal diffusivity, or good chemical stability) it may be possible to use substitution or doping to bring $M(\frac{1}{2})$ substantially closer to its theoretical limit.

As noted above, the figure of merit for operation in the CFS mode is not $M(\frac{1}{2})$ but $M(1)$. In addition, it can be shown (1) that if the target is sufficiently thin or the dielectric constant sufficiently high that resolution is limited by capacitive lag, the appropriate figure of merit is $M(1)$, independent of readout mode or amplifier bandwidth. Returning to Eq. (4), we find for $n = 1$

$$M(1) = \frac{\alpha E}{4\pi \kappa T}$$

If we restrict our attention to ferroelectric crystals, Eq. (8) can be analyzed with the aid of the recently developed generalized molecular field theory of ferroelectricity (4). In this theory the crystal is regarded as an array of $N$ electric dipoles of moment $\mu$ which interact via a local field $E'$, which is the same at each dipole site and given by

$$E' = E + f(P),$$

where $E$ is the macroscopic (applied) electric field, and $f$ is an arbitrary odd function of the polarization $P$. It is readily shown that if the dipoles are free to assume any orientation, then the polarization is given by

$$P/N\mu = (\coth x - 1/x)$$

where

$$x = \mu E' / kT$$
Since \( N_p \) is the largest polarization possible in this model, it can be determined by extrapolating the observed spontaneous polarization to \( T = 0 \). Equation (10) can be solved numerically to give \( x \) as a function of \( P/N_p \), and the results are shown in Fig. 2.

The generalized molecular field theory also gives

\[
\frac{\varphi_E}{\chi_T} = \frac{N_p \lambda x}{3T_o},
\]

where \( T_o \) is the Curie-Weiss temperature and \( \lambda = (df/dP)_{P=0} \) is the Lorentz factor. Equations (8) and (12) yield

\[
M(1) = \frac{\alpha}{4\pi C_p} \frac{N_p \lambda}{3T_o} x.
\]

Garn and Sharp (1) have used Eq. (1) to evaluate \( M(1) \) from the experimental data for a number of ferroelectric crystals, assuming \( \alpha = 1 \). Working backward from these results for \( M(1) \), using experimental values for \( T_o, N_p, \) and \( \lambda \), and estimating \( C_p \) as in the case of \( M(\frac{1}{2}) \), we have used Eq. (13) to determine the value of \( x \), and the corresponding \( P/N_p \) from Eq. (10), needed to account for the observed \( M(1) \). The values required, shown in Table I, are quite reasonable, with \( x \) always of the order of one and \( P/N_p \) varying from 0.13 for TGSe quite near its Curie temperature to 0.74 for triglycine fluoberyllate (TGFB).

For reference purposes we have also listed the experimental values of \( \lambda \) obtained from the relation \( \lambda = 4nT_o/C \), where \( C \) is the Curie constant.

### TABLE I

<table>
<thead>
<tr>
<th>Material</th>
<th>( M(1) )</th>
<th>x</th>
<th>( P/N_p )</th>
<th>( \lambda )</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>( \times 10^{-10} \text{C cm/J} )</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>TGS</td>
<td>2.6</td>
<td>1.6</td>
<td>0.46</td>
<td>1.14</td>
</tr>
<tr>
<td>TGFB</td>
<td>8.4</td>
<td>3.9</td>
<td>0.74</td>
<td>1.72</td>
</tr>
<tr>
<td>TGSe</td>
<td>0.42</td>
<td>0.4</td>
<td>0.13</td>
<td>0.93</td>
</tr>
<tr>
<td>NaN03</td>
<td>3.2</td>
<td>1.3</td>
<td>0.39</td>
<td>0.83</td>
</tr>
<tr>
<td>BaTiO3</td>
<td>0.42</td>
<td>2.9</td>
<td>0.66</td>
<td>0.033</td>
</tr>
<tr>
<td>LiTaO3</td>
<td>1.2</td>
<td>3.0</td>
<td>0.67</td>
<td>0.070</td>
</tr>
</tbody>
</table>
These results suggest that Eq. (13) can be used to estimate the largest value of \( M(1) \) one might reasonably expect to find in a ferroelectric crystal. The Lorentz factor \( \lambda \) is not likely to exceed the value \( \lambda = \frac{4\pi}{3} \) appropriate to point dipoles on a cubic lattice. (No material studied experimentally has been found to have a \( \lambda \) significantly higher than this.) To maximize \( M(1) \) at room temperature we must have \( T \) only slightly higher than 300 K, and for convenience we choose \( 3T = 1000 \) K. There is more uncertainty in estimating an upper bound for \( N_0 \), but we must note the well-known fact (5) that all known ferroelectrics fall into one of two classes: those with relatively modest spontaneous polarization and Curie constants of the order of \( 10^3 \), and those with a larger polarization and Curie constants of the order of \( 10^7 \). The latter class, consisting mainly of oxygen-octahedral ferroelectrics like BaTiO\(_3\) or LiTaO\(_3\), will have Lorentz factors much smaller than \( \frac{4\pi}{3} \), and so cannot yield large values of \( M(1) \). In terms of the spontaneous polarization, the dividing line between the two classes seems to lie near \( 10 \) \( \mu \)C/cm\(^2\) (5), so we will take this as an estimate of the largest \( N_0 \) likely to be found in a material with a large \( \lambda \). Finally, we take \( x = 2 \), since Fig. 3 shows this to be within a factor of two of the exact result throughout the range \( 0.4 < P/N_0 < 0.8 \). (Larger values of \( N_0 \) are unlikely on the assumption that \( T \) is only slightly above room temperature.) With these values for the parameters appearing in Eq. (13), one obtains \( M(1) = 2.7 \times 10^{-9} \) C-cm/J, or just a factor of three larger than the value for TGF. Despite considerable uncertainty in this estimate, it seems reasonable to conclude that the existence of a ferroelectric crystal with \( M(1) \) an order of magnitude greater than that of TGF is most improbable; such a material would require properties quite unlike those of any known ferroelectric.
THERMAL DIFFUSION

The thermal modulation transfer function has the form (1)

\[ F = F_0 \left( 1 + y^2 \right)^{-\frac{1}{2}} \]  

where \( F \) and \( y \) depend on whether the incident radiation is modulated by chopping or by panning the camera:

\[
F_0 = \begin{cases} 
1, & \text{chopping} \\
\sin \theta, & \text{panning}
\end{cases} 
\]

\[ y = \begin{cases} 
2\pi \delta N^2 / f, & \text{chopping} \\
2\pi \delta N / v, & \text{panning}
\end{cases} \]  

where \( \theta = \pi N v t_f \),

and \( \delta = \) thermal diffusivity

\( N = \) image resolution

\( f = \) chopper frequency

\( v = \) panning velocity

\( t_f = \) panning time constant

At low resolution (\( y \ll 1 \)) we have \( F \sim 1 \) for either form of modulation. The effect of thermal diffusion on resolution can be examined by defining a critical resolution \( N_c \) at which \( F \) has fallen to some fraction of its low-resolution value, where the fraction chosen depends on the contrast reduction at high spatial frequencies which is acceptable in a given application. It is easily shown that

\[ N_c \propto \begin{cases} 
1/\delta^{\frac{1}{2}}, & \text{chopping} \\
1/\delta, & \text{panning}
\end{cases} \]  

(16)

demonstrating that while both modulation schemes benefit from reduced thermal diffusivity, the relative improvement is greater for panning. We can now show that in principle \( F \) can be increased by reducing \( \delta \), i.e., \( F \) and \( M(n) \) vary independently from one material to another.

The thermal diffusivity is the ratio of the thermal conductivity \( \kappa \) to the specific heat:

\[ \delta = \kappa / C_p \]  

and the thermal conductivity can be written as
where \( v \) is an average phonon velocity and \( \ell \) and \( \tau \) the average phonon mean free path and scattering time, respectively. In the Debye model (6) \( v \) is proportional to the Debye temperature \( \Theta \). In most crystals at room temperature, \( \tau \) is dominated by phonon-phonon scattering and can be shown (7) to be proportional to \( \Theta/T \). We then have

\[
\delta = \ell \tau = A\Theta^3/T,
\]

where the coefficient \( A \) is nearly independent of the material chosen (7). The results of the previous section show that although \( M(n) \) depends on \( \Theta \) through \( C_p \), this dependence has practically disappeared at room temperature since \( T/\Theta \) is then large enough to bring \( C_p \) close to its limiting value of \( 3k \) per atomic volume. As a result, it is possible in principle to reduce \( \delta \) without affecting \( M(n) \). It is clear from Eq. (19) that materials with low Debye temperatures should be sought, i.e. materials which are "soft" in the sense of having small elastic stiffnesses and low sound velocities. The strong dependence of \( N \) on \( \Theta \) suggests that substantial improvements can be made in this way.

CONCLUSIONS

We have considered the influence of the physical properties of pyroelectric materials on their performance as vidicon targets. The signal-to-noise figure of merit \( M(\frac{1}{2}) \), relevant to anode potential stabilized vidicon operation (and to small area detectors), was found to be subject to a theoretical limit dictated by thermodynamic considerations. This figure of merit can be increased substantially within a family of structurally related materials, but it was shown that presently available materials already realize as much as 40% of the theoretical maximum. The figure of merit \( M(1) \), relevant to cathode potential stabilized vidicon operation (and to target-capacitance limited operation in either readout mode) was studied with the aid of recent developments in the theory of ferroelectricity. Although no firm upper limit was obtained for this figure of merit, evidence was presented which indicates that only modest improvement over presently available materials is likely. Analysis of the problem of thermal diffusion shows that materials with low Debye temperatures should be sought and that the relative improvement in resolution obtained in this way is greater if the image is modulated by panning rather than chopping.
ACKNOWLEDGEMENTS

One of the authors (M.I.B.) is grateful to L.E. Garn and E. Singer for helpful discussions. This work was supported by the Defense Advanced Research Projects Agency under contract DAAB 07-74-C-0470.

REFERENCES

(6) M. Born and K. Huang, Dynamical Theory of Crystal Lattices (Oxford University Press, New York, 1954) Chap. II.

Figure Captions

Figure 1. The figure of merit M(1/2) from Ref. 1 as a function of the dimensionless variable (X/1+X)1/2.

Figure 2. Solutions of the polarization equation P/Nµ = cothx - 1/x.
Fig. 2

\[ p = \frac{P}{N\mu} \]

\[ x = \frac{\mu E_\zeta}{kT} \]
# DISTRIBUTION LIST

<table>
<thead>
<tr>
<th>No.</th>
<th>Organization</th>
<th>Address</th>
</tr>
</thead>
<tbody>
<tr>
<td>101</td>
<td>Defense Documentation Center</td>
<td>Cameron Station (Bldg 5), Alexandria, Virginia 22314</td>
</tr>
<tr>
<td>107</td>
<td>Director National Security Agency</td>
<td>Fort George G. Meade, MD 20755</td>
</tr>
<tr>
<td>108</td>
<td>Director, Defense Nuclear Agy</td>
<td>Washington, DC 20305</td>
</tr>
<tr>
<td>200</td>
<td>Office of Naval Research</td>
<td>Arlington, VA 22217</td>
</tr>
<tr>
<td>203</td>
<td>Naval Ship Engineering Center</td>
<td>Hyattsville, MD 20782</td>
</tr>
<tr>
<td>206</td>
<td>Commander Naval Electronics Lab Ctr</td>
<td>San Diego, California 92152</td>
</tr>
<tr>
<td>207</td>
<td>Commander US Naval Ordnance Lab</td>
<td>White Oak, Silver Spring, MD 20910</td>
</tr>
<tr>
<td>210</td>
<td>Commandant, Marine Corps</td>
<td>Washington, DC 20380</td>
</tr>
<tr>
<td>212</td>
<td>Communications-Electronics Div</td>
<td>Quantico, Virginia 22134</td>
</tr>
<tr>
<td>217</td>
<td>Naval Air Systems Command</td>
<td>Washington, DC 20325</td>
</tr>
<tr>
<td>301</td>
<td>Rome Air Development Center</td>
<td>Griffiss AFB, New York 13440</td>
</tr>
<tr>
<td>307</td>
<td>Hq ESD(TRI)</td>
<td>Bedford, MA 01730</td>
</tr>
<tr>
<td>309</td>
<td>Air Force Avionics Lab</td>
<td>Wright-Patterson AFB, Ohio 45433</td>
</tr>
<tr>
<td>310</td>
<td>Recon Central/RSA</td>
<td>Wright-Patterson AFB, Ohio 45433</td>
</tr>
<tr>
<td>314</td>
<td>Hq, Air Force Systems Cmd</td>
<td>Andrews AFB 20331</td>
</tr>
<tr>
<td>315</td>
<td>Director Air University Library</td>
<td>Maxwell AFB, Alabama 36112</td>
</tr>
<tr>
<td>319</td>
<td>Air Force Weapons Laboratory</td>
<td>Kirtland AFB, New Mexico 87117</td>
</tr>
<tr>
<td>400</td>
<td>HQDA(DAMT-ZA)</td>
<td>Washington, DC 20310</td>
</tr>
<tr>
<td>405</td>
<td>Ofc, Asst Sec of the Army (R&amp;D)</td>
<td>Washington, DC 20310</td>
</tr>
<tr>
<td>408</td>
<td>HQDA(DARD-ARP/Dr R.B. Watson)</td>
<td>Washington, DC 20310</td>
</tr>
<tr>
<td>409</td>
<td>Commanding General US Army Materiel Command</td>
<td>Alexandria, Virginia 22333</td>
</tr>
</tbody>
</table>
Commanding General
US Army Materiel Command
ATTN: DRCRD-0
5001 Eisenhower Ave.
Alexandria, VA 22333

Commanding General
US Army Missile Command
ATTN: DRSMI-RR
(Dr. J. P. Hallowes)
Redstone Arsenal, Alabama 35809

CG, US Army Missile Command
Redstone Scientific Info Ctr
ATTN: Chief, Document Sect
Redstone Arsenal, Alabama 35809

Commanding General
US Army Weapons Command
ATTN: DRSWE-REF
Rock Island, Illinois 61201

Commanding Officer
Vint Hills Farm Station
ATTN: Ch, Systems Engrg Div
Ops Center
Virginia 22186

Commanding Officer
US Army Ordnance School
ATTN: ATSOR-CTD
Aberdeen Proving Ground, MD 21005

Commander
US Army Intelligence School
ATTN: ATSIT-CTD
Fort Huachuca, AZ 85613

Hq, US Army Aviation Syl Cmd
ATTN: DRSAV-C-AD
P.O. Box 209
St. Louis, Missouri 63166

Commanding Officer
Harry Diamond Laboratories
ATTN: Library
Washington, D.C. 20438

CO, USA Foreign Sci & Tech Ctr
ATTN: DRXSIT-15I
220 Seventh St, NE
Charlottesville, VA 22901

CO, USA Foreign Science Div
ATTN: AMXST CE Division
220 Seventh St, NE
Charlottesville, Virginia 22901

Commanding Officer
Picatinny Arsenal
ATTN: SMUPA-TV1
Dover, N. J. 07801

Commanding Officer
Picatinny Arsenal
ATTN: SMUPA-RT-S, Bldg 59
Dover, N. J. 07801

Commanding Officer
Frankford Arsenal
ATTN: L8400 (Dr. W. McNeill)
Philadelphia, PA 19137

Commanding Officer
US Army Materials and Mech
Research Center
ATTN: DRXMR-ATL Tech Lib Br
Watertown, Mass. 02172

President
US Army Artillery Board
Fort Sill, Oklahoma 73503

Commanding Officer
Aberdeen Proving Ground
ATTN: Tech Library, Bldg 313
Aberdeen Proving Gr, MD 21005

Commanding Officer
Aberdeen Proving Ground
ATTN: STEAP-TL
Aberdeen Proving Gr, MD 21005

Commanding Officer
USASA Test and Evaluation Cen
Fort Huachuca, Arizona 85613

Commanding Officer
US Army Research Office-Durham
ATTN: CRDARD-IP
Box CM, Duke Station
Durham, N. C. 27706
607 Commanding General
USA Tank-Automotive Command
ATTN: DRSTA-Z, Dr. J. Parks
001 Warren, Michigan 48090

610 Director
Night Vision Lab (USAECOM)
ATTN: DRSEL-NV-D
001 Fort Belvoir, Virginia 22060

614 Chief
Ofc of Missile Electronic Warfare
Electronic Warfare Lab, ECOM
001 White Sands Missile Range, NM 88002

616 CG, USA Electronics Command
ATTN: DRSEL-PP/P-TED
(Mr. C. Mogavero)
225 South 18th Street
001 Philadelphia, PA. 19103

617 Chief, Intel Materiel Dev & Support
Ofc, Electronic Warfare Lab, (ECOM)01
001 Fort Meade, MD 20755

680 Commanding General
US Army Electronics Command
000 Fort Monmouth, N. J. 07703

1D RSEL-NV-D 1D RSEL-RD
1D RSEL-NL-D 1D RSEL-WL-D 1D RSEL-TL-D
1D RSEL-VL-D 1D RSEL-CT-D
1D RSEL-CL-D 1D RSEL-TL-DT
60 RSEL -TL-ES

1D RSEL-TE

2D RSEL-M5-TI
1D RSEL-OG-TD
1D RSEL-EN
1D RSEL-PA
1USMC-LNO
1 DRSEL-PP-C-ES-1

703 NASA Sci & Tech Info Facility
ATTN: Acquisitions Br(S-AK/DL)
P.O. Box 33
002 College Park, Maryland 20740

705 Advisory Gp on Electron Devices
201 Varick St. 9th Floor
002 New York, New York 10014

706 Advisory Gp on Electron Devices
ATTN: Secy, Sp Gr on Opt Masers
201 Varick Street
002 New York, New York 10014

708 Ballistic Msl Radiation Anal Cen
Univ of Mich., Willow Run Lab
Institute of Science & Tech
001 PO Box 618, Ann Arbor, Michigan 48107

711 Metals and Ceramics Inf Center
Battelle
505 King Avenue
Columbus, Ohio 43201

712 Elec Properties Info Center
Hughes Aircraft Company
Centinela and Teale Streets
001 Culver City, California 90230

715 Plastics Tech Eval Center
Picatinny Arsenal, Hldg 3401
001 Dover, N. J. 07801

717 Reliability Analysis Center
Rome Air Development Center
ATTN: J.M. Schramp/RCRM
001 Griffiss AFB, New York 13440

718 Remote Area Conflict Info Ctr
Battelle Memorial Institute
505 King Avenue
001 Columbus, Ohio 43201

719 Shock and Vibration Info Center
Naval Research Lab (Code 6020)
001 Washington, D. C. 20390

# Op number specified in contract. Add COTR's
* line symbol.